

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Y. KIMURA, et al.
Application No.: 10/019,407
Filed: March 25, 2002
For: POLYCRYSTALLINE SEMICONDUCTOR THIN FILM
SUBSTRATE, MANUFACTURING METHOD OF THE SAME,
SEMICONDUCTOR DEVICE AND ELECTRONIC DEVICE
Art Unit: 2812
Examiner: Unknown

INFORMATION DISCLOSURE STATEMENT
UNDER 37 CFR §§ 1.97 & 1.98

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

March 12, 2004

Sir:

Pursuant to Applicants' duty of disclosure, enclosed please find copies of documents cited in connection with a Chinese Patent Application corresponding to the above-identified application. Also enclosed is Form PTO/SB/08A, listing the enclosed documents.

This Information Disclosure Statement is being submitted, on information and belief, before the mailing date of a first office action on the merits.

To the extent the documents listed on the attached form PTO/SB/08A are not in the English language, the requirement of 37 CFR '1.98(a)(3) for a concise explanation of the relevance is satisfied by an English abstract attached thereto.

It is respectfully requested that this Information Disclosure Statement be considered by the Examiner.


Application No.: 10/019,407

Docket No.: 520.41003X00

Please charge any shortage in the fees due in connection with the filing of this paper, including extension of time fees, to the deposit account of Antonelli, Terry, Stout & Kraus, LLP, Deposit Account No. 01-2135 (Docket No. 520.41003X00) please credit any excess fees to such deposit account.

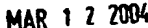
Respectfully submitted,

ANTONELLI, TERRY, STOUT & KRAUS, LLP

By 
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JP 11-145056

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OTHER PRIOR ART—NON PATENT LITERATURE DOCUMENTS

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**Examiner
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Considered

¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard St.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

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